



### **50V PNP POWER SWITCHING TRANSISTOR IN SOT89**

### **Features**

- BV<sub>CEO</sub> > -50V
- I<sub>C</sub> = -2A High Continuous Collector Current
- · High Gain Holds Up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

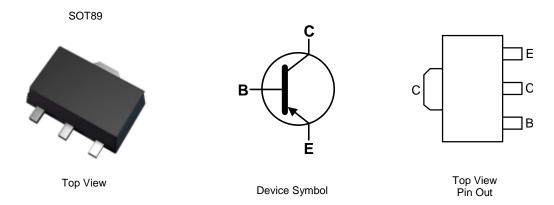
https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.052 grams (Approximate)



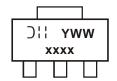
### **Ordering Information** (Note 4)

Part Number	Status	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
2DA1213O-13	Obsolete	P25X	13	12	2,500
2DA1213Y-13	Active	P25Y	13	12	2,500
2DA1213Y-13R	Active	P25Y	13	12	4,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



xxxx = Product Type Marking Code P25X = 2DA1213O P25Y = 2DA1213Y YWW = Date Code Marking Y = Last Digit of Year (ex: 1 = 2021) WW = Week Code 01 to 53

2DA1213O/Y Document number: DS31306 Rev. 6 - 2 1 of 6

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### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	V
Emitter-Base Voltage	VEBO	-6	V
Continuous Collector Current	Ic	-2	Α
Peak Pulse Current	I <sub>CM</sub>	-2.5	Α
Base Current	I <sub>B</sub>	-500	mA

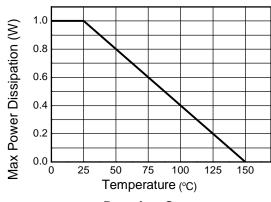
## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	Rejl	18.3	°C/W
Operating and Storage Temperature Range	$T_{J}, T_{STG}$	-55 to +150	°C

Notes:

- 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

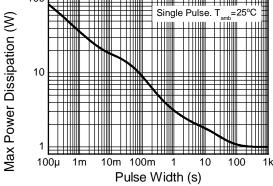
## **Thermal Characteristics and Derating Information**



Thermal Resistance (°C/W) 100 20 Pulse Width (s)

**Derating Curve** 

**Transient Thermal Impedance** 100



**Pulse Power Dissipation** 



# **Electrical Characteristics** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage		ВУсво	-50	_	_	V	Ic = -100μA	
Collector-Emitter Breakdown Voltage (Note 7)		BV <sub>CEO</sub>	-50	_	_	V	I <sub>C</sub> = -10mA	
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-6	_	_	V	I <sub>E</sub> = -100μA	
Collector Cut-Off Current		I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -50V	
Emitter Cut-Off Current		I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5V	
	2DA1213O		70		140		Ic = -500mA, VcE = -2V	
DC Current Gain (Note 7)	2DA1213Y	hFE	120	_	240	<u> </u>	Ic = -500mA, VcE = -2V	
	2DA1213O, 2DA1213Y		20		_		Ic = -2A, VcE = -2V	
Collector-Emitter Saturation	Voltage (Note 7)	V <sub>CE(sat)</sub>	_	_	-0.5	V	$I_C = -1A$ , $I_B = -50mA$	
Base-Emitter Turn-On Voltage (Note 7)		V <sub>BE(sat)</sub>	_	_	-1.2	V	Ic = -1A, I <sub>B</sub> = -50mA	
Transition Frequency		fτ	_	160	_	MHz	Ic = -100mA, VcE = -2V, f = 100MHz	
Output Capacitance		Cobo	_	17	_	pF	Vcb = -10V, IE = 0, f = 1MHz	
Turn-On Time		t <sub>on</sub>	_	25	_	ns	V 0V I- 4A	
Storage Time		t <sub>(s)</sub>	_	130	_	ns	Vce = -2V, Ic = -1A, I <sub>B1</sub> = -I <sub>B2</sub> = -50mA	
Fall Time		t <sub>(f)</sub>	_	12	_	ns	1B1 = -1B2 = -50ffA	

Note:

# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

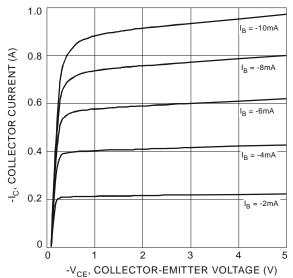


Figure 1 Typical Collector Current vs. Collector-Emitter Voltage

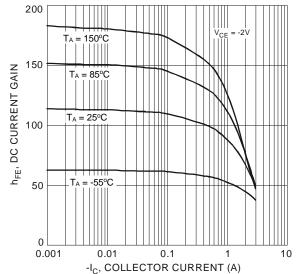


Figure 2 Typical DC Current Gain vs. Collector Current (2DA12130)

<sup>7.</sup> Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# $\textbf{Typical Electrical Characteristics} \ (@T_A = +\underline{25}^{\circ}C, \text{ unless otherwise specified.}) \ (\text{continued})$

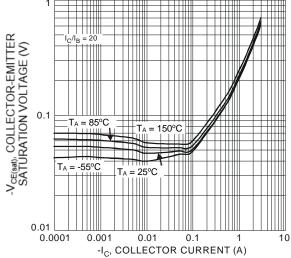


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

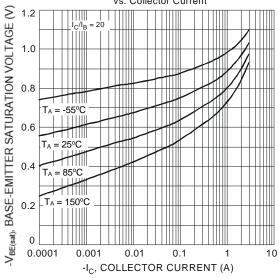


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

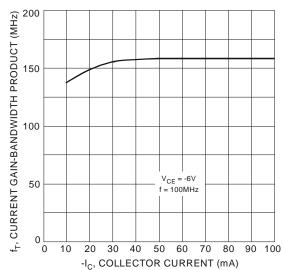


Figure 7 Typical Gain-Bandwidth Product vs. Collector Current

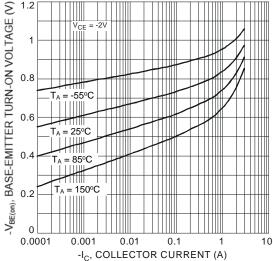


Figure 4 Typical Base-Emitter Turn-On Voltage

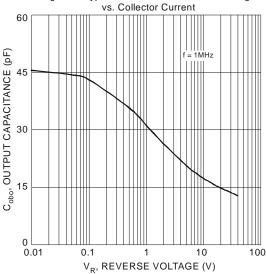


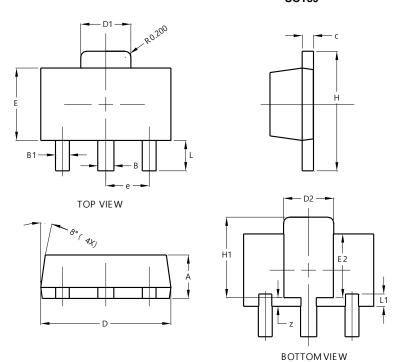
Figure 6 Typical Output Capacitance Characteristics



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT89**

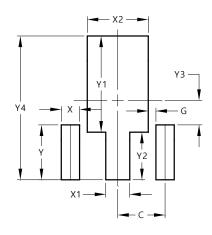


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT89**



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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